

PRODUCT/PROCESS CHANGE NOTIFICATION

PCN IPD-DIS/13/8107 Dated 07 Oct 2013

Protection Arrays in SO-8 Package housed in Morocco plant (BSK) / ECOPACK2 / Cu wire bonding / NiPdAgAu plating conversion

Table 1. Change Implementation Schedule

Forecasted implementation date for change	01-Oct-2013
Forecasted availability date of samples for customer	30-Sep-2013
Forecasted date for STMicroelectronics change Qualification Plan results availability	30-Sep-2013
Estimated date of changed product first shipment	06-Jan-2014

Table 2. Change Identification

Product Identification (Product Family/Commercial Product)	Protection Arrays in SO-8 Package
Type of change	Package assembly material change
Reason for change	package industrial optimization
Description of the change	Change 1 : ECOPACK2 conversion ("Halogen free") Change 2 : Implementation of copper wire bonding and related leadframe NiPdAu pre-plating
Change Product Identification	internal codification, marking, labelling and QA number
Manufacturing Location(s)	

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	Tab	le 3.	List	of	Attac	hments
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Customer Part numbers list	
Qualification Plan results	

Customer Acknowledgement of Receipt	PCN IPD-DIS/13/8107
Please sign and return to STMicroelectronics Sales Office	Dated 07 Oct 2013
□ Qualification Plan Denied	Name:
□ Qualification Plan Approved	Title:
	Company:
□ Change Denied	Date:
□ Change Approved	Signature:
Remark	

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DOCUMENT APPROVAL

Name	Function
Paris, Eric	Marketing Manager
Nopper, Christian	Product Manager
Cazaubon, Guy	Q.A. Manager

A7/.



PCN Product/Process Change Notification

Protection Arrays in SO-8 Package housed in Morocco plant (BSK):

ECOPACK®2 / Cu wire bonding / NiPdAgAu plating conversion

Notification number:	IPD-DIS/13/8107	Issue Date	30/09/2013
Issued by	Aline AUGIS		<u>I</u>
Product series affected by	y the change	USB6B1RLY	
		USB6B1RLY	
		USB6B1RLY	
		DA108S1	
		DA108S1RL	
		DA112S1	
		DA112S1RL	
		DALC112S1 DALC112S1RL	
		ESDA25B1	
		ESDA25B1RL	
		ESDA6V1U1	
		ESDA6V1U1RL	
		ITA10B1	
		ITA18B1	
		ITA18B1RL	
		ITA25B1	
		ITA25B1RL	
		ITA6V1U1	
		ITA6V1U1RL	
		ITA6V5B1	
		ITA6V5B1RL	
		ITA6V5C1RL	
		USB6B1	
		USB6B1	
		USB6B1	
		USB6B1RL	
		USB6B1RL	
		USB6B1RL	
Type of change		Package assembly material	change

Issue date 30-09-2013 1/3



(1) IPG: Industrial & Power Group - ASD: Application Specific Device − IPAD™: Integrated Passive and Active Devices

Description of the change

Change 1: ECOPACK®2 conversion ("Halogen free")

Change 2: Implementation of copper wire bonding and related leadframe NiPdAu pre-plating

	BEFORE CHANGE	AFTER CHANGE
Leadframe	NiPdAu	NiPdAgAu
Glue	EN4900ST10	Ablestik 8601
Molding compound	ECOPACK1	ECOPACK2
Wire	Au 2 mils/0.8mils	Cu 2 mils/ 1 mils

Reason for change

<u>Change 1</u>: ST is converting **products** housed in **SO8 package** from the standard molding compound to the ECOPACK[®]2 grade compound (so called Halogen free)

Change 2: ST's SO8 package industrial optimization.

Former versus changed product:

The changed products do not present modified electrical, dimensional or thermal parameters, leaving unchanged the current information published in the product datasheet The Moisture Sensitivity Level of the part (according to the IPC/JEDEC JSTD-020D standard) remains unchanged. The footprint recommended by ST remain the same. There is no change in the packing modes and the standard delivery quantities either.

Disposition of former products

Deliveries of former product versions will continue while the conversion is brought to completion and as long as former product stocks last.

Marking and traceability

New internal codification, product marking/labeling and QA number.

An additional letter "G" is printed to the right of the "e4" symbol for the ECOPACK®2 conversion.







Qualification complete date

 8^{th} of April, 2013

Issue date 30-09-2013 2/3

STMicroelectronics IPG - ASD & IPAD™ Division¹ BU Protection and IPADs



(1) IPG: Industrial & Power Group - ASD: Application Specific Device – IPAD™: Integrated Passive and Active Devices

Forecasted sample availability

Product family	Package	Commercial part Number	Availability date
Protection	SO8	USB6B1	Week 40-2013
Protection	SO8	ESDA25B1	Week 40-2013
Protection	SO8	DA112S1	Week 40-2013

Change implementation schedule

Sales types	Estimated production start	Estimated first shipments
All	Week 40-2013	Week 02-2014
	r	

Comments:

Customer's feedback

Please contact your local ST sales representative or quality contact for requests concerning this change notification.

Absence of acknowledgement of this PCN within 30 days of receipt will constitute acceptance of the change Absence of additional response within 90 days of receipt of this PCN will constitute acceptance of the change

Qualification program and results	N°1288QRP-Rev 2 Attached
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Issue date 30-09-2013 3/3



Reliability Report Protection Arrays in SO-8 Package ECOPACK®2 / Cu wire / NiPdAgAu plating conversion

General Information

Product Line Protection

Part-number Refer to the table below

Product Group IPD

Product division ASD&IPAD **Package** S08

Maturity level step Qualification Locations

STMicroelectronics Tours Wafer fab

(France)

STMicroelectronics

Assembly plant Bouskoura (Morocco)

Reliability Lab STMicroelectronics Tours

The **involved product** series are listed below:

Package	Product Family	Involved Series or Product
SO-8	Protection	DA1xxS1(RL) DALC112S1(RL) ESDA25B1(RL) ESDA6V1U1(RL) ITAxxB1(RL) USB6B1(RL) USB6B1RLY

DOCUMENT INFORMATION

Version	Date	Pages	Prepared by	Approved by	Comment
1	26-November-	8	J. MICHELON	J.P. REBRASSE	First issue
	2012				(Reference document: Product
					Change Notification
					PCN IPD-DIS/12/7253)

Note: This report is a summary of the reliability trials performed in good faith by STMicroelectronics in order to evaluate the potential reliability risks during the product life using a set of defined test methods.

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1 APPLICABLE AND REFERENCE DOCUMENTS

Document reference	Short description
AEC-Q100	Stress test qualification for automotive grade integrated circuits
AEC-Q101	Stress test qualification for automotive grade discrete semiconductors
JESD47H	Stress-Test-Driven Qualification of Integrated Circuits

2 GLOSSARY

DUT	Device Under Test
PCB	Printed Circuit Board
SS	Sample Size

3 RELIABILITY EVALUATION OVERVIEW

3.1 Objectives

The ECOPACK® program is the cornerstone of our efforts for being leader in offering **environmentally friendly packaging**. Progressing in this program, ST is implementing technical solutions designed to progressively remove banned substances from manufacturing.

To meet the so called "Halogen-Free" requirements of the market, ST is converting its **Protection Arrays** in **SO-8 package** to the **ECOPACK**® grade.

The permanent evolution of our technology leads us to implement at the same time the **copper wire bonding process** instead of gold and the NiPdAgAu plating, for the considered parts.

3.2 **Product reliability description**

The qualification methodology is failure mechanisms driven (JESD94). All potential failure mechanisms have been identified. Reliability trials follow automotive standard AEC-Q101, JESD47 and 0061692 ST specifications.

3.3 Conclusion

Based on the reliability results, plan requirements have been fulfilled without exception and are compliant to AEC-Q101 requirements. It shows that the devices behave correctly against environmental tests (no failure). Moreover, the stability of electrical parameters during the accelerated tests demonstrates the robustness of the products and safe operation, which is consequently expected during their lifetime.



4 DEVICE CHARACTERISTICS

4.1 **Device description**

The assembly Bill of Material status is summarized in the table below.

Material	SO-8 package					
iviaterial	Current	New				
Lead frame finishing	NiPdAu (Pd thickness = 30nm)	NiPdAgAu (Pd thickness = 10nm)				
Die attach glue material	ECOPACK®1	ECOPACK®2				
Wire bonding	Au 0.8-2 mils	Cu 1-2 mils				
Molding compound	ECOPACK®1	ECOPACK®2				

5 TESTS RESULTS SUMMARY

5.1 **Test vehicle**

Lot #	Part Number	Die manufacturing plant	Package	Assembly Plant	Comments
Lot 1	USB6B1RLY			STMicroelectronics	Qualification lot
Lot 2	DALC112S1	STMicroelectronics	SO8	Bouskoura	Qualification lot
Lot 3	ITA25B1	Tours (France)		(Morocco)	Qualification lot
Lot 4	ITA25B1				Qualification lot



5.2 Test plan and results summary

USB6B1RLY

Toot	Test PC St		Conditions	SS	Stone	Failure/SS	Note
rest	PC	Std ref.	Conditions	33	Steps	Lot 1	Note
package	Orie	nted Tests					
Precond	Υ	JESD22 A- 113	MSL 1: Ta = 85°C; RH = 85%	25	168h	0/25	MSL 1 compliant
					168h	0/77	DPA after THB
THB	Υ	JESD22 A- 101	Ta = 85°C; RH = 85% VR = 5,25V	77	504h	0/77	compliant to
					1000h	0/77	AEC-Q101
		JESD22 A- 104	[-65°C +150C]; 2 cycles/hour		100 cycles	0/77	DPA after TC compliant to AEC-Q101
TC	Υ			77	500 cycles	0/77	
					1000 cycles	0/77	
AC	Υ	JESD22 A- 102	Ta = 121°C / RH = 100% / P=2 Bars	77	96h	0/77	
die Orien	ted	Tests					
			11 - 15030 VR - 5 250		168h	0/77	
HTRB	N	JESD22 A- 108		77	504h	0/77	
		, ,			1000h	0/77	

DALC112S1

						E '1 (00	
Test	РС	Std ref.	Conditions	SS	Steps	Failure/SS	Note
1631	. 0	ota rei.		Oteps	Lot 2	14010	
Package	Orie	nted Tests					
Precond	Υ	JESD22 A- 113	MSL 1: Ta = 85°C; RH = 85%	25	168h	0/25	MSL 1 compliant
		IECD00 A			168h	0/77	DPA after THB
THB	Υ	JESD22 A- 101	Ta = 85°C / RH = 85% / VR = 18V	77	504h	0/77	compliant to
		101			1000h	0/77	AEĊ-Q101
		, JESD22 A- 104	[-65°C +150C]; 2 cycles/hour		100 cycles	0/77	DPA after TC compliant to AEC-Q101
TC	Υ			77	500 cycles	0/77	
					1000 cycles	0/77	ALC-Q101
AC	Υ	JESD22 A- 102	Ta = 121°C / RH = 100% / P=2 Bars	77	96h	0/77	
Die Oriented Tests							
		IECD33 A			168h	0/77	
HTRB	Ν	JESD22 A- 108	Tj = 150°C / VR = 18V	77	504h	0/77	
		100			1000h	0/77	



ITA25B1

	DC		Conditions	cc	Steps	Failure/SS		Note
Test	PC	Std ref.	Conditions	SS		Lot 3	Lot 4	Note
Package	Orie	nted Tests						
Precond	Υ	JESD22 A- 113	MSL 1: Ta = 85°C; RH = 85%	25	168h	0/25	N/A	MSL1 compliant
					168h	0/77	N/A	DPA after THB
THB	Υ	JESD22 A- 101	Ta = 85°C / RH = 85% / VR = 24V	77	504h	0/77	N/A	compliant to AEC-Q101
					1000h	0/77	N/A	
		JESD22 A- 104	[-65°C +150C]; 2 Cycles/hour	154	100 cycles	0/77	0/77	DPA after TC compliant to AEC-Q101
TC	Υ				500 cycles	0/77	0/77	
					1000 cycles	0/77	0/77	
AC	Υ	JESD22 A- 102	Ta = 121°C / RH = 100% / P=2 Bars	77	96h	0/77	N/A	
Die Orien	ted	Tests						
					168h	0/77	N/A	
HTRB	N	JESD22 A- 108	1 11 = 125°(2: VR = 24V 1	77	504h	0/77	N/A	
					1000h	0/77	N/A	



6 ANNEXES

6.1 **Tests Description**

Test name	Description	Purpose		
Die Oriented				
HTRB High Temperature Reverse Bias	The device is stressed in static configuration, trying to satisfy as much as possible the following conditions: low power dissipation; max. supply voltage compatible with diffusion process and internal circuitry limitations;	To determine the effects of bias conditions and temperature on solid state devices over time. It simulates the devices' operating condition in an accelerated way. To maximize the electrical field across either reverse-biased junctions or dielectric layers, in order to investigate the failure modes linked to mobile contamination, oxide ageing, layout sensitivity to surface effects.		
Package Oriented				
PC Preconditioning	The device is submitted to a typical temperature profile used for surface mounting devices, after a controlled moisture absorption.	As stand-alone test: to investigate the moisture sensitivity level. As preconditioning before other reliability tests: to verify that the surface mounting stress does not impact on the subsequent reliability performance. The typical failure modes are "pop corn" effect and delamination.		
TC Temperature Cycling	The device is submitted to cycled temperature excursions, between a hot and a cold chamber in air atmosphere.	To investigate failure modes related to the thermo-mechanical stress induced by the different thermal expansion of the materials interacting in the die-package system. Typical failure modes are linked to metal displacement, dielectric cracking, molding compound delamination, wire-bonds failure, die-attach layer degradation.		
THB Temperature Humidity Bias	The device is biased in static configuration minimizing its internal power dissipation, and stored at controlled conditions of ambient temperature and relative humidity.	To evaluate the package moisture resistance with electrical field applied, both electrolytic and galvanic corrosion are put in evidence.		
AC Auto Clave (Pressure Pot)	The device is stored in saturated steam, at fixed and controlled conditions of pressure and temperature.	To investigate corrosion phenomena affecting die or package materials, related to chemical contamination and package hermeticity.		

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PCN Title: Protection Arrays in SO-8 Package housed in Morocco plant (BSK) / ECOPACK2 / Cu wire bonding / NiPdAgAu plating conversion

PCN Reference : IPD-DIS/13/8107 PCN Created on : 01-OCT-2013

Subject : Public Products List

Dear Customer,

Please find below the Standard Public Products List impacted by the change:

ST COMMERCIAL PRODUCT

DA108S1 DA108S1RL DA112S1 DA112S1RL DALC112S1 DALC112S1RL ESDA25B1 ESDA25B1RL ESDA6V1U1 ESDA6V1U1RL ITA10B1 ITA18B1 ITA18B1RL ITA25B1 ITA25B1RL ITA6V1U1 ITA6V1U1RL ITA6V5B1 ITA6V5B1RL USB6B1 USB6B1RL

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